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February 2012

FAN7387V Ballast Control IC for Compact Fluorescent Lamp

Features

- Integrated Half-Bridge MOSFET
- Internal Clock Using RCT
- Enable External Sync Function Using RCT
- Dead-Time Control by using Resistor
- Shut Down (Disable Mode)
- Internal Shunt Regulator
- UVLO Function High and Low Side

Applications

Compact Fluorescent Lamp Ballast

Description

The FAN7387V, developed using Fairchild's unique high-voltage process and system-in-package (SiP) concept, is a ballast-control integrated circuit (IC) for a compact fluorescent lamp (CFL). The FAN7387V has a simple oscillating circuit using an external resistor and capacitor so the frequency variation is stable across the temperature range. FAN7387V has a external pin for dead time control and shutdown. By using this resistor, a designer can choose the optimum dead time to reduce the power loss on internal switching devices (MOSFETs).

8-DIP



Ordering Information

Part Number	Operating Temperature	Package	Packing Method	
FAN7387VN	-40 to +125°C	8-Lead, Dual-In-line Package (DIP)	Tube	

Typical Applications Diagrams

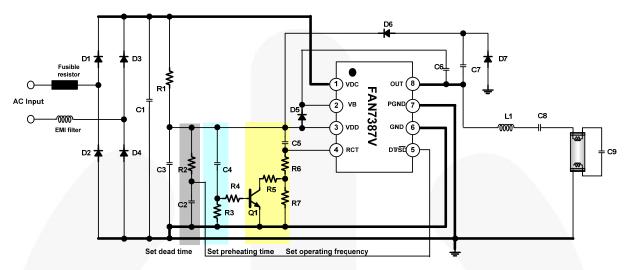


Figure 1. Typical Application Circuit for Fluorescent Lamp (Rapid Starting Method without PTC)

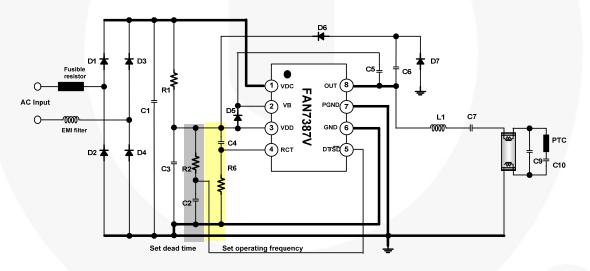


Figure 2. Typical Application Circuit for Fluorescent Lamp (Rapid Starting Method with PTC)

Internal Block Diagram

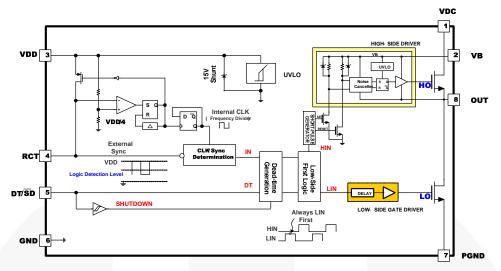


Figure 3. Functional Block Diagram

Pin Configuration

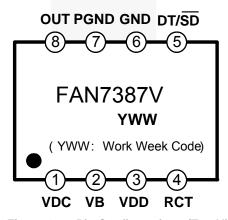


Figure 4. Pin Configurations (Top View)

Pin Definitions

Pin#	Name	Description	
1	VDC	High-voltage Supply	
2	VB	High-Side Floating Supply	
3	VDD	Supply Voltage	
4	RCT	Oscillator Frequency Set Resistor and Capacitor	
5	DT/SD	Dead Time Set Resistor	
6	GND	Signal Ground	
7	PGND	Power Ground	
8	OUT	High-Side Floating Supply Return	

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. $T_A=25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Min.	Тур.	Max.	Unit
VB	High-Side Floating Supply	-0.3		465.0	V
V _{OUT}	High-Side Floating Supply Return	-0.3		440.0	V
V _{RCT}	RCT Pins Input Voltage		V_{DD}		V
I _{CL}	Clamping Current Level ⁽¹⁾			25	mA
dV _{OUT} /dt	Allowable Offset Voltage Slew Rate		50		V/ns
T _A	Operating Temperature Range	-40		+125	°C
T _{STG}	Storage Temperature Range	-65		+150	°C
P _D	Power Dissipation		2.1		W
Θ_{JA}	Thermal Resistance (Junction-to-Air)		70		°C/W

Note:

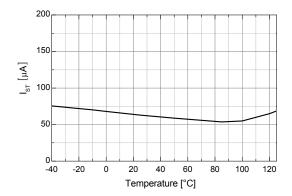
 Do not supply a low-impedance voltage source to the internal clamping Zener diode between the GND and the VDD pin of this device.

Electrical Characteristics

 V_{BIAS} (V_DD, V_B -V_OUT)=14.0V, $T_A = 25^{\circ}C,$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
High Vol	age Supply Section						
V_{DC}	High Voltage Supply Voltage		440			V	
Low-Side	Supply Characteristics (V _{DD})			1			
VDD _{UV+}	V _{DD} UVLO Positive-Going Threshold	V _{DD} Increasing	9	11	13		
VDD _{UV-}	V _{DD} UVLO Negative-Going Threshold	V _{DD} Decreasing	7.8	8.8	9.8	1 ,,	
VDD _{UHY}	V _{DD} -Side UVLO Hysteresis			2.2		V	
V_{CL}	Supply Camping Voltage I _{DD} =10mA 14.4 15.4			1			
I _{ST}	Startup Supply Current	V _{DD} =9V		60	90	μА	
I_{QDD}	Low-Side Quiescent Supply Current	R_{DT} =100k Ω		230	380		
I _{DD}	Dynamic Operating Supply Current	20kHz, C _L =1nF		0.6		mA	
High-Sid	e Supply Characteristics (VB-V _{OUT})						
V _{HSUV+}	High-Side UVLO Positive-Going Threshold	V _B -V _{OUT} Increasing	8	9	10		
V _{HSUV-}	High-Side UVLO Negative-Going Threshold	V _B -V _{OUT} Decreasing	7.5	8.5	9.5	V	
V _{HSUHY}	V _{BS} Supply UVLO Hysteresis			0.5		1	
I _{QHS}	High-Side Quiescent Supply Current			50	90		
I _{PBS}	High-Side Dynamic Operating Supply Current	20kHz, C _L =1nF		130	180	μA	
Oscillato	r Characteristics						
f _{osc}	Oscillation Frequency	R_T =50k Ω , C_T =330pF	18	20	22	kHz	
D	Duty Cycle	Running Mode	47.5	49.0		%	
V _{RCT+}	Upper Threshold Voltage of RCT	Running Mode		V_{DD}			
V _{RCT} -	Lower Threshold Voltage of RCT	Running Mode		V _{DD} /4		1,,	
V _{IH}	Logic "1" Input Voltage of RCT	Running Mode		3/4 V _{DD}		V	
V _{IL}	Logic "0" Input Voltage of RCT	Running Mode		/	3/5 V _{DD}		
t _D	Dead Time	R_{DT} =100k Ω	440	540	640		
t _{DMIN}	Minimum Dead Time	$V_{DT/SD}=V_{DD}$	280	400	520	ns	
Protectio	n Characteristics				y y		
V _{SD+}	Shutdown "1" Input Voltage		2.5			.,,	
V _{SD-}	Shutdown "0" Input Voltage	V _{SD/DT} =0 After Run			1	V	
I _{SD}	Shutdown Current	Mode			350	μA	
t _{SD}	Shutdown Propagation Delay			180		Ns	
Internal N	MOSFET Section					7	
I _{LKMOS}	Internal MOSFET Leakage Current	V _{DS} =400V			50	μA	
R _{ON}	Static Drain-Source On-Resistance	V _{GS} =10V, I _D =190mA		4.6	6.0	Ω	
I _S	Maximum Continuous Drain-Source Diode Forward Current	35 . 5		0.38		Α	
I _{SM}	Maximum Pulsed Continuous Drain-Source Diode Forward Current			3.04		Α	
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} =0V, I _S =0.38A			1.2	V	

Typical Performance Characteristics



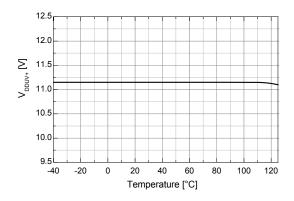


Figure 5. Startup Current vs. Temperature

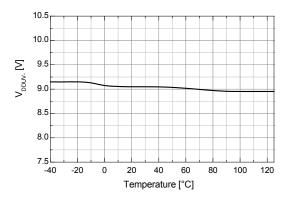


Figure 6. V_{DD} UVLO+ vs. Temperature

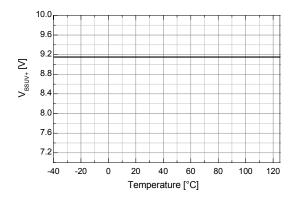


Figure 7. V_{DD} UVLO- vs. Temperature

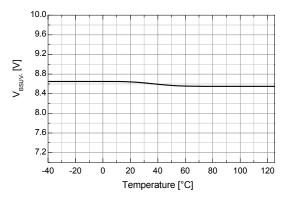


Figure 8. $VB_{\cdot}V_{OUT}$ UVLO+ vs. Temperature

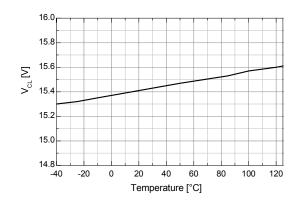
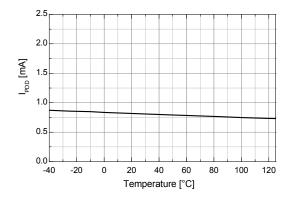


Figure 9. VB_.V_{OUT} UVLO- vs. Temperature

Figure 10. V_{CL} vs. Temperature

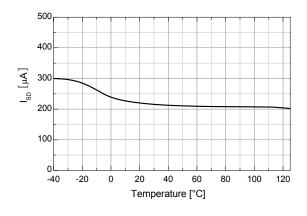
Typical Performance Characteristics (Continued)



500 400 400 200 100 -40 -20 0 20 40 60 80 100 120 Temperature [°C]

Figure 11. I_{PDD} vs. Temperature

Figure 12. I_{QDD} vs. Temperature



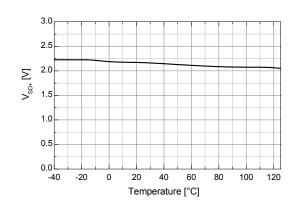
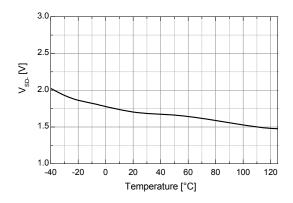


Figure 13. I_{SD} vs. Temperature

Figure 14. V_{SD}+ vs. Temperature



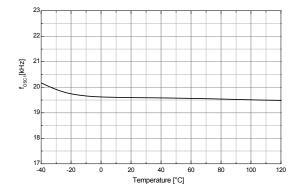
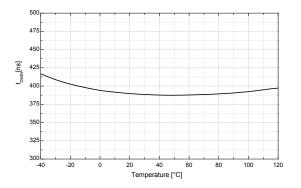


Figure 15. V_{SD}- vs. Temperature

Figure 16. Operating Frequency vs. Temperature

Typical Performance Characteristics (Continued)



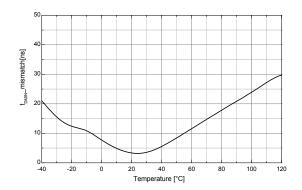
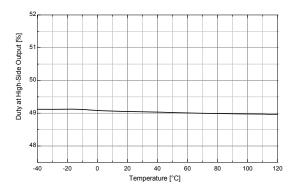


Figure 17. t_{DMIN} vs. Temperature

Figure 18. Dead-Time Mismatch vs. Temperature



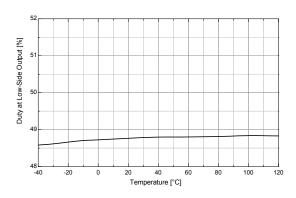
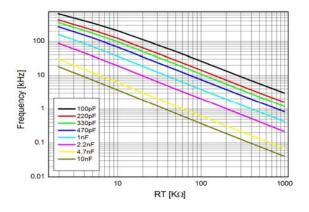


Figure 19. High-Side Duty Ratio vs. Temperature

Figure 20. Low-Side Duty Ratio vs. Temperature



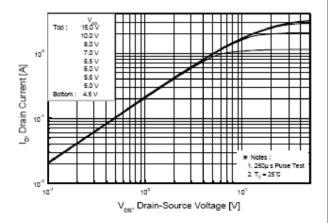


Figure 21. Frequency vs. R_T

Figure 22. On-Region Characteristics

Typical Performance Characteristics (Continued)

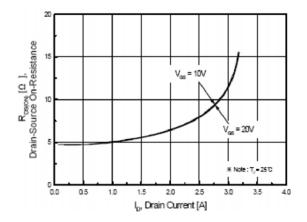


Figure 23. On-Resistance Variation vs.
Drain Current and Gate Voltage

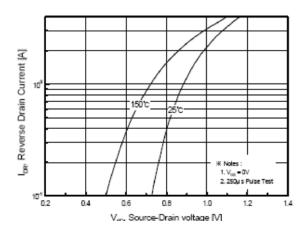


Figure 24. Body Diode Forward Voltage Variation vs.
Source Current and Temperature

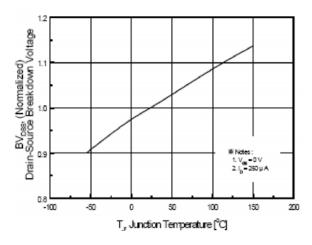


Figure 25. Breakdown Voltage Variation vs. Temperature

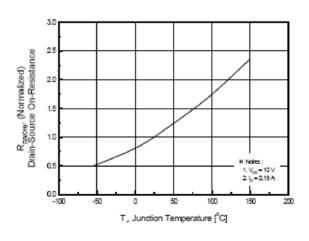


Figure 26. On-Resistance Variation vs. Temperature

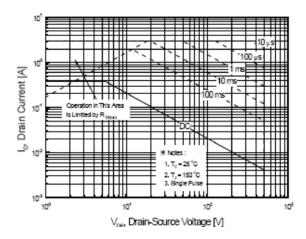


Figure 27. Maximum Safe Operating Area

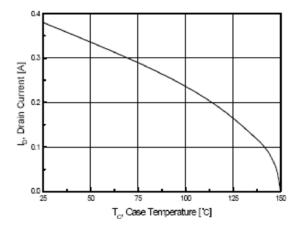


Figure 28. Maximum Drain-Current vs. Case Temperature

Application Information

1. Under-Voltage Lockout (UVLO) Function

FAN7387V has a UVLO circuit for a low-side and high-side block. When V_{DD} reaches to the VDD $_{UV}+$, the UVLO circuit is released and the FAN7387V operates normally. At UVLO condition, the FAN7387V has a low supply current of less than 130 μ A. Once UVLO is released, FAN7387V operates normally until V_{DD} goes below VDD $_{UV}-$, the UVLO hysteresis. FAN7387V also has a high-side gate driver. The supply for the high-side driver is applied between VB and $V_{OUT}.$ To prevent malfunction at low supply voltage between VB and V_{OUT} , FAN7387V provides an additional UVLO circuit. If VB-V $_{OUT}$ is under $V_{HSUV}+$, the driver holds LOW state to turn off the high-side switch. Once the voltage of VB-V $_{OUT}$ is higher than $V_{HSUV}+$, after VB-V $_{OUT}$ exceeds $V_{HSUV}-$, the operation of driver resumes.

2. Oscillator

The running frequency is determined by an external timing resistor (R_T) and timing capacitor (C_T). The charge time of capacitor C_T from 1/4 V_{DD} to V_{DD} determines the running frequency of gate driver output (V_{OUT}).

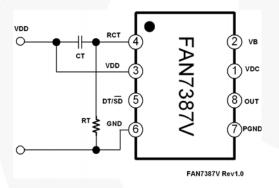


Figure 29. Typical Connection Method

Figure 30 shows the typical waveforms of RCT and internal signals (LO and HO) of IC. From the circuit analysis, the discharging time of RCT, t, is given by:

$$V_{RCT}(t) = V_{DD} \times In \left(\frac{-t}{R_T \cdot C_T} \right)$$
 (1)

From Equation 1, it is possible to calculate the discharging time, t, from V_{DD} to one quarter (1/4) of V_{DD} by substituting $V_{RCT(t)}$ with 1/4 $V_{DD}.$

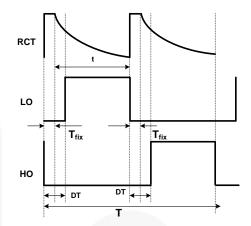


Figure 30. Typical Waveforms of RCT and Internal Signal (LO, HO) of IC

$$t = 1.38 \bullet R_T \bullet C_T \tag{2}$$

The running frequency of IC is determined by 1/t and is approximately given as:

$$f_{\text{running}} = \frac{1}{t} = \frac{1}{2(t + t_{\text{fiv}})}$$
 (3)

where t is the discharging time of the RCT voltage and $t_{\rm fix}$ is constant value about 450ns of IC.

3. Programming Dead Time Control / Shutdown

A multi-function pin controls dead time using an external resistor (R_{DT}) and protects abnormal condition using an external switch. This pin should be connected to an external capacitor to maintain stable operation.

If the voltage of DT/SD is decreased to under 1V by an external switch, such as the TR or MOSFET, the FAN7387V enters shutdown mode. In this mode, the FAN7387V doesn't have any output signal.

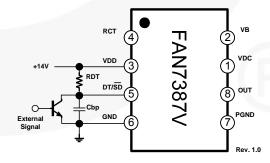
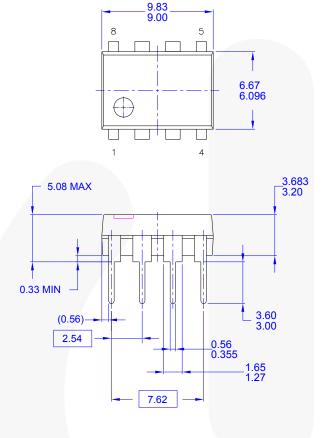
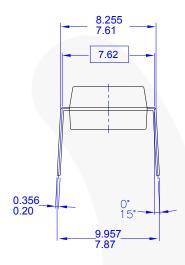


Figure 31. External Shutdown Circuit

Physical Dimensions





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- B) ALL DIMENSIONS ARE IN MILLIMETERS.
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Figure 32. 8-Lead Dual Inline Package (DIP)

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Definition of Terms

Definition of Terms		
Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
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